

Ultra-linear Mixer with Integrated IF Amp and LO Buffer

Description

CMY213 is a general purpose down-converter device designed for receiver applications such as cellular and PCS mobile phones, ISM bands, GPS receivers, L-band satellite terminals, WLAN and pagers. It is particularly suited for CDMA receiver applications due to its excellent intermodulation characteristics and its high conversion gain.

The device combines an ultra-linear mixer with LO - driver and a single stage IF-amplifier in a very small SCT598 package. The mixer section of CMY213 combines low conversion losses and excellent intermodulation characteristics with low requirements of LO - and DC-power. The internal level controlled LO-Buffer enables a good performance over a wide LO level range. The input and output matching of the IF amplifier can be adapted externally within a frequency range from 45 to 250 MHz.

Features

 Typical overall performance at cellular frequencies (for P_{LO} = -5dBm operation conditions: 3V, 8 mA; f_{RF} = 850 MHz; f_{LO} = 740 MHz):

Gain: 9.5 dB

Input IP3: 10 dBmNoise figure: 8 dB

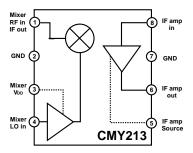
RF-frequency range 0.5 - 2.5 GHz
Operating voltage range: 2.6 to 5V

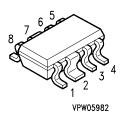
Small SCT598 plastic package

Applications

- Down Converter for Multiple Wireless Applications
- Cellular and PCS Mobile Phones
- Particularly Suited for CDMA Receivers
- ISM and WLAN Receivers
- GPS Receivers

Package Outline and Pin Configuration, SCT598





CMY213 Datasheet

Maximum Ratings

| Parameter | Port | Symbol | Value | | Unit |
|-----------------------------------|------|--------------------|-------|-------|------|
| | | | min | max | |
| Supply Voltage | 3,6 | V_{DD} | 0 | 5 | V |
| DC-Voltage at LO Input | 4 | V ₆ | -3 | 0,5 | V |
| DC-Voltage at Mixer RF-IF Port | 1 | V ₈ | - 0,5 | + 0,5 | V |
| Power into Mixer RF Port | 1 | P_{RF} | | 10 | dBm |
| Power into LO Input | 4 | P _{in,LO} | -10 | 10 | dBm |
| Channel Temperature | | T _{Ch} | | 150 | °C |
| Operating Temperature | | T _{op} | -30 | 85 | °C |
| Storage Temperature | | T _{stg} | -55 | 150 | °C |
| Thermal Resistance* | | | | | |
| Channel to Soldering Point (GND) | | R _{thChS} | 260 | | K/W |

Electrical Characteristics

| Parameter, | Comment | min | typ | max | Unit |
|----------------------|----------------|-----|-----|-----|------|
| RF - frequency range | external match | 0.5 | - | 2.5 | GHz |
| LO - Frequency range | external match | 0.5 | - | 2.5 | GHz |
| IF Frequency range | external match | 45 | | 250 | MHz |

Typical performance at cellular frequencies*:

 T_a = 25°C; V_{DD} = 3V, f_{RF} = 850MHz; f_{LO} = 740MHz; P_{LO} = -5dBm; f_{IF} = 110MHz, Z_s = Z_L = 50 Ohm; unless otherwise specified

| Parameter, Test Conditions | Symbol | min | typ | max | Unit |
|--|------------------|-----|-----|-----|------|
| Total operating Current (Mixer + IF amplifier) | I _{op} | - | 8.0 | 9.5 | mA |
| Conversion Gain | G _c | 8.0 | 9.5 | - | dB |
| SSB Noise Figure | F _{ssb} | - | 8 | - | dB |
| RF Input -/ IF Output return loss (external matching required) | RFIrl / IFOrl | - | 10 | - | dB |
| 3rd Order Input Intercept Point | IIP3 | 8 | 10 | - | dBm |
| LO-RF Isolation | Iso | - | 10 | - | DB |

Test conditions at PCS frequencies:

 T_a = 25°C; V_{DD} = 3V, f_{RF} = 1960MHz; f_{LO} = 1750MHz; P_{LO} = -5dBm; f_{IF} = 210MHz, Z_{S} = Z_{L} = 50 Ohm; unless otherwise specified

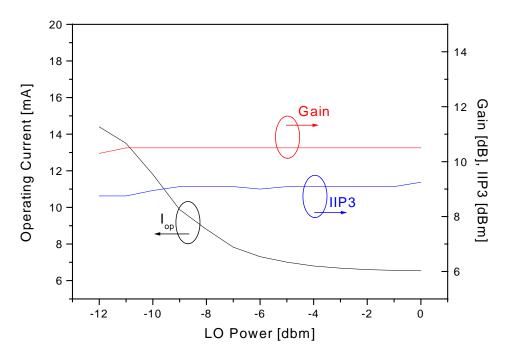
| Parameter, Test Conditions | Symbol | min | typ | max | Unit |
|--|------------------|-----|-----|-----|------|
| Total operating Current (Mixer + IF amplifier) | I _{op} | - | 8.0 | 9.5 | mA |
| Conversion Gain | G _c | 7 | 8.5 | - | dB |
| SSB Noise Figure | F _{ssb} | - | 8.5 | - | dB |
| RF Input -/ IF output return loss (external matching required) | RFIrl / IFOrl | - | 10 | - | dB |
| 3rd Order Input Intercept Point | IIP3 | 10 | 12 | - | dBm |
| LO-RF Isolation | Iso | - | 6 | - | dB |

^{*} IMPORTANT NOTE:

During production, the RF performance at PCS frequencies is screened. The passed devices also achieve the specified RF performance at cellular frequencies.

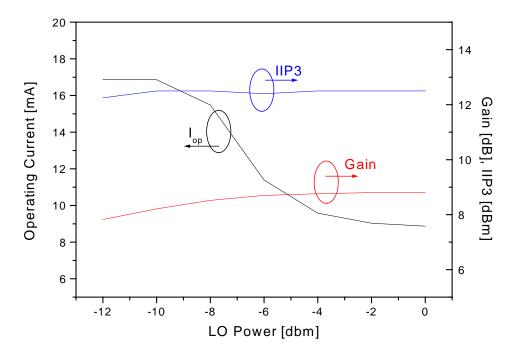
Typical device behavior at cellular frequencies:

 $T_a = 25$ °C; $V_{DD} = 3$ V, $f_{RF} = 850$ MHz; $f_{LO} = 740$ MHz; $f_{IF} = 110$ MHz, $Z_s = Z_L = 50$ Ohm; unless otherwise specified

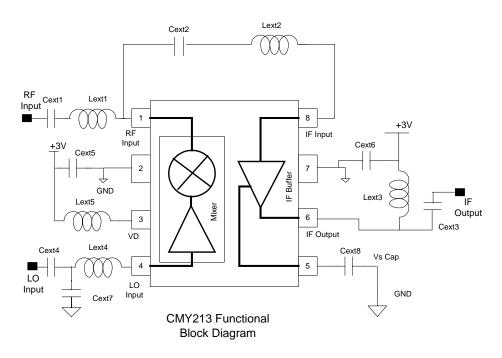


Typical device behavior at PCS frequencies:

 T_a = 25°C; V_{DD} = 3V, f_{RF} = 1960MHz; f_{LO} = 1750MHz; f_{IF} = 210MHz, Z_{S} = Z_{L} = 50 Ohm; unless otherwise specified



Applications Information Test circuit / application example



External components for cellular frequencies

 $f_{RF} = 850MHz$; $f_{LO} = 740MHz$; $f_{IF} = 110MHz$

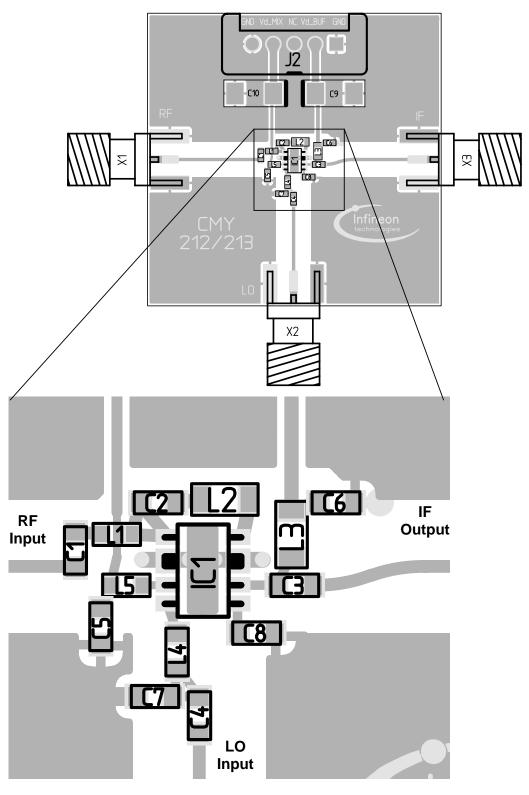
| Capacitors | (Murata 0402) | Inductors | (Toko) |
|------------|---------------|-----------|-----------------------|
| Cext1 | 1.5 pF | Lext1 | 27 nH <i>LL1005</i> |
| Cext2 | 1 nF | Lext2 | 180 nH <i>LL1608</i> |
| Cext3 | 18 pF | Lext3 | 150 nH <i>LL160</i> 8 |
| Cext4 | 100 pF | Lext4 | 27 nH <i>LL1005</i> |
| Cext5 | 1 nF | Lext5 | 27 nH <i>LL1005</i> |
| Cext6 | 1 nF | | |
| Cext7 | 3 pF | | |
| Cext8 | 100 nF | | |

External components for PCS frequencies

 $f_{RF} = 1960MHz$; $f_{LO} = 1750MHz$; $f_{IF} = 210MHz$

| Capacitors | (Murata 0402) | Inductors | (Toko) |
|------------|---------------|-----------|----------------------|
| Cext1 | 1 pF | Lext1 | 5.6 nH <i>LL1005</i> |
| Cext2 | 1 nF | Lext2 | 68 nH <i>LL1608</i> |
| Cext3 | 8 pF | Lext3 | 68 nH <i>LL1608</i> |
| Cext4 | 22 pF | Lext4 | 4.7 nH <i>LL1005</i> |
| Cext5 | 1 nF | Lext5 | 4.7 nH <i>LL1005</i> |
| Cext6 | 1 nF | | |
| Cext7 | 3 pF | | |
| Cext8 | 100 nF | | |

Applications Information (cont)PCB-Layout Size: 35 x 35 mm²



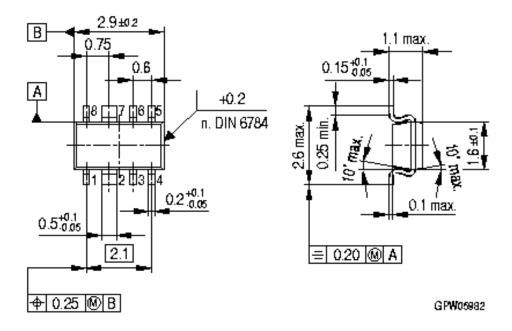
For additional information and latest specifications, see our website: www.triquint.com Revision C, September 12, 2006

General description and notes

CMY213 is a general purpose down-converter device designed for multiple applications such as cellular and PCS mobile phones, ISM bands, GPS receivers, L-band satellite terminals, WLAN and pagers. Due to its excellent intermodulation characteristics and its high conversion gain, CMY213 is particularly suited for CDMA receiver applications.

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Semiconductor Device Outline SCT598-8-1



Ordering Information

| Туре | Marking | Ordering code (tape and reel) | Package ¹⁾ |
|--------|---------|-------------------------------|-----------------------|
| CMY213 | 213 | CMY213 | SCT598-8-1 |

Additional Information

This part is compliant with RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

The part is rated Moisture Sensitivity Level 1 at 260°C per JEDEC standard IPC/JEDEC J-STD-020.

ESD: Electrostatic discharge sensitive device. Observe handling Precautions.

For latest specifications, additional product information, worldwide sales and distribution locations, and information about TriQuint:

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